ACST4

Overvoltage protected AC switch

Features

- Triac with overvoltage protection
- Low I_{GT} (<10 mA) or high immunity (I_{GT}<35 mA) version
- High noise immunity: static dV/dt > 1000 V/µs
- TO-220FPAB insulated package: 1500 V rms

Benefits

- Enables equipment to meet IEC 61000-4-5
- High off-state reliability with planar technology
- Needs no external overvoltage protection
- Reduces the power passive component count
- High immunity against fast transients described in IEC 61000-4-4 standards

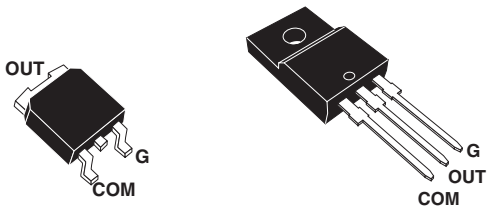
Applications

- AC mains static switching in appliance and industrial control systems
- Drive of medium power AC loads such as:
  - Universal motor of washing machine drum
  - Compressor for fridge or air conditioner

Description

The ACST4 series belongs to the ACS™/ACST power switch family built with A.S.D.® (application specific discrete) technology. This high performance device is suited to home appliances or industrial systems, and drives loads up to 4 A.

This ACST4 switch embeds a Triac structure and a high voltage clamping device able to absorb the inductive turn-off energy and withstand line transients such as those described in the IEC 61000-4-5 standards. The ACST410 needs only a low gate current to be activated (I_{GT} < 10 mA) and still shows a high noise immunity complying with IEC standards such as IEC 61000-4-4 (fast transient burst test).



DPAK
ACST410-8B
ACST435-8B

TO-220FPAB
ACST410-8FP
ACST435-8FP

Figure 1. Functional diagram

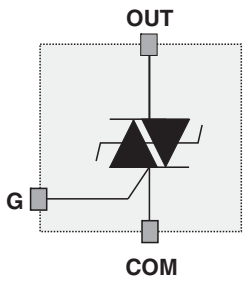


Table 1. Device summary

Symbol	Value	Unit
$I_{T(RMS)}$	4	A
V_{DRM}/V_{RRM}	800	V
I_{GT} (ACST410)	10	mA
I_{GT} (ACST435)	35	mA

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1 Characteristics

Table 2. Absolute ratings (limiting values)

Symbol	Parameter			Value	Unit
$I_{T(RMS)}$	On-state rms current (full sine wave)	TO-220FPAB	T_c = 102 °C	4	A
		DPAK	T_c = 112 °C		
		DPAK with 0.5 cm^2 copper	T_{amb} = 60 °C	1	
I_{TSM}	Non repetitive surge peak on-state current T_j initial = 25 °C, (full cycle sine wave)	F = 60 Hz	t_p = 16.7 ms	32	A
		F = 50 Hz	t_p = 20 ms	30	A
I^2t	I^2t for fuse selection		t_p = 10 ms	6	A^2s
dI/dt	Critical rate of rise on-state current I_G = 2 x $I_{GT,}$ ($t_r \leq$ 100 ns)	F = 120 Hz	T_j = 125 °C	100	A/µs
V_{PP}	Non repetitive line peak pulse voltage (1)		T_j = 25 °C	2	kV
$P_{G(AV)}$	Average gate power dissipation		T_j = 125 °C	0.1	W
P_{GM}	Peak gate power dissipation (t_p = 20 µs)		T_j = 125 °C	10	W
I_{GM}	Peak gate current (t_p = 20 µs)		T_j = 125 °C	1.6	A
T_{stg}	Storage temperature range			-40 to +150	°C
T_j	Operating junction temperature range			-40 to +125	°C
T_l	Maximum lead solder temperature during 10 ms (at 3 mm from plastic case)			260	°C
$V_{INS(RMS)}$	Insulation rms voltage	TO-220FPAB		1500	V

1. According to test described in IEC 61000-4-5 standard and *Figure 19.*

Table 3. Electrical characteristics

Symbol	Test conditions	Quadrant	T_j		ACST410	ACST435	Unit
I_{GT} (1)	V_{OUT} = 12 V, R_L = 33 Ω	I - II - III	25 °C	MAX.	10	35	mA
V_{GT}	V_{OUT} = 12 V, R_L = 33 Ω	I - II - III	25 °C	MAX.	1.0	1.1	V
V_{GD}	V_{OUT} = V_{DRM}, R_L = 3.3 kΩ	I - II - III	125 °C	MIN.	0.2		V
I_H (2)	I_{OUT} = 500 mA		25 °C	MAX.	20	25	mA
I_L	I_G = 1.2 x I_{GT}	I - II - III	25 °C	MAX.	40	60	mA
dV/dt (2)	V_{OUT} = 67 % V_{DRM}, gate open		125 °C	MIN.	500	1000	V/µs
$(dI/dt)_c$ (2)	Without snubber		125 °C	MIN.		5	A/ms
$(dI/dt)_c$ (2)	$(dV/dt)_c$ = 15 V/µs		125 °C		2		A/ms
V_{CL}	I_{CL} = 0.1 mA, t_p = 1 ms		25 °C	MIN.	850		V

1. Minimum I_{GT} is guaranteed at 5% of I_{GT} max
2. For both polarities of OUT pin referenced to COM pin

Table 4. Static characteristics

Symbol	Test conditions			Value	Unit
V_{TM}(1)	I_{OUT} = 5.6 A, t_p = 500 µs	T_j = 25 °C	MAX.	1.7	V
V_{T0}(1)	Threshold voltage	T_j = 125 °C	MAX.	0.9	V
R_d(1)	Dynamic resistance	T_j = 125 °C	MAX.	110	mΩ
I_{DRM} I_{RRM}	V_{OUT} = V_{DRM}/ V_{RRM}	T_j = 25 °C	MAX.	20	µA
		T_j = 125 °C	MAX.	500	µA

1. For both polarities of OUT pin referenced to COM pin

Table 5. Thermal resistances

Symbol	Parameter		Value	Unit
$Rt_{h(j-a)}$	Junction to ambient	TO-220FPAB	60	°C/W
	Junction to ambient (soldered on 0.5 cm^2 copper pad)	DPAK	70	
$R_{th(j-c)}$	Junction to case for full cycle sine wave conduction	TO-220FPAB	4.6	°C/W
		DPAK	2.6	

Figure 2. Maximum power dissipation versus on-state rms current

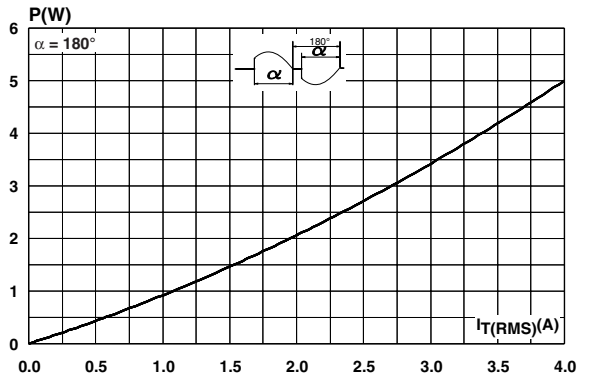


Figure 3. On-state rms current versus case temperature (full cycle)

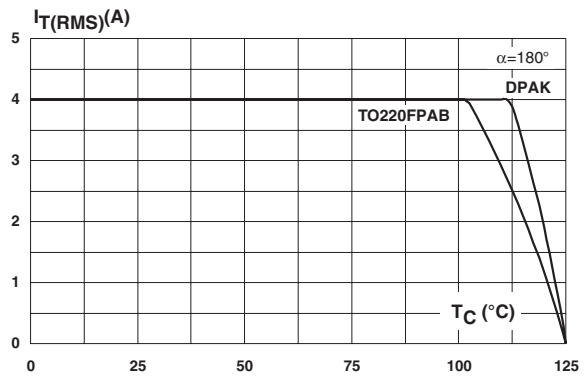


Figure 4. On-state rms current versus ambient temperature (free air convection, full cycle)

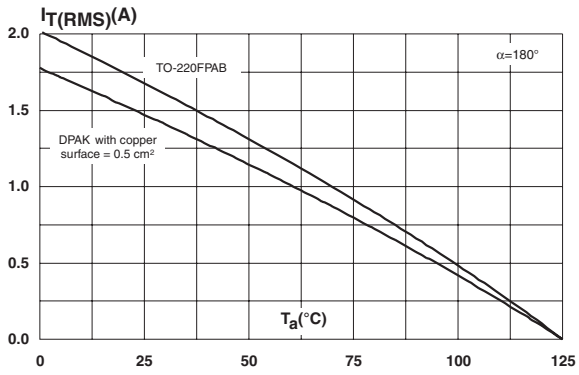


Figure 5. Relative variation of thermal impedance versus pulse duration

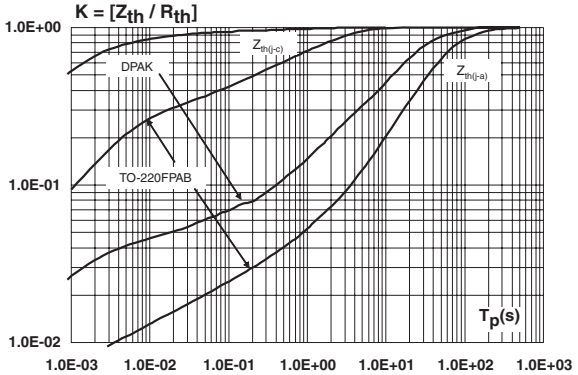


Figure 6. Relative variation of gate trigger current (I_{GT}) and voltage (V_{GT}) versus junction temperature

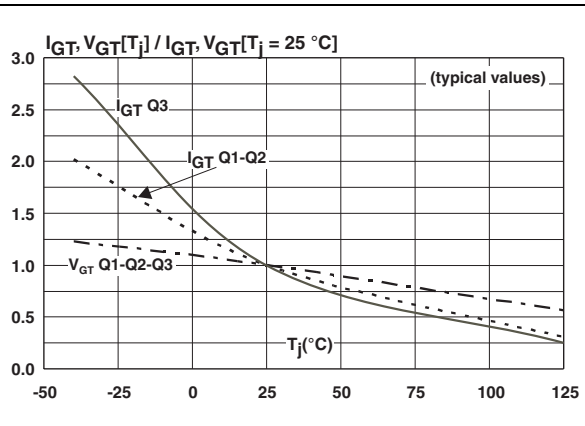


Figure 7. Relative variation of holding current (I_H) and latching current (I_L) versus junction temperature

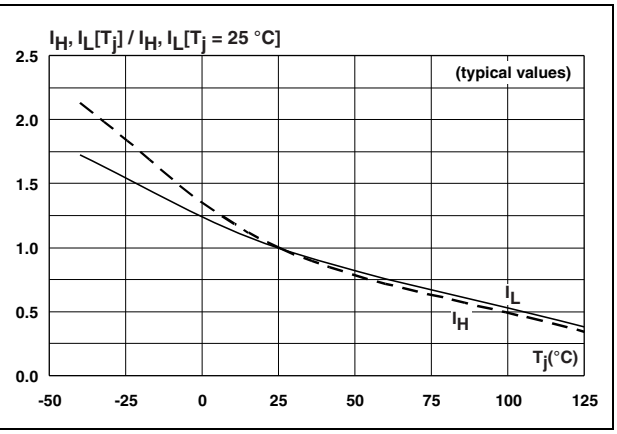


Figure 8. Surge peak on-state current versus number of cycles

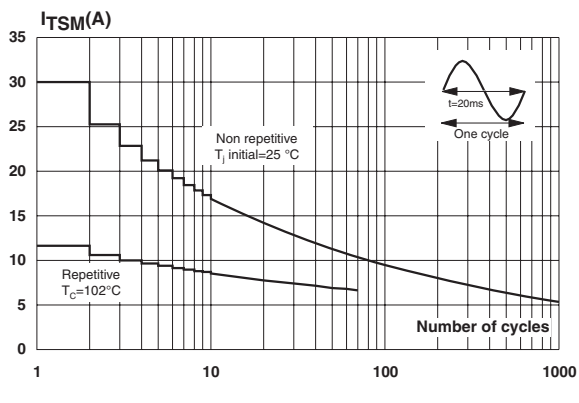


Figure 9. Non repetitive surge peak on-state current and corresponding value of I^2t versus sinusoidal pulse width

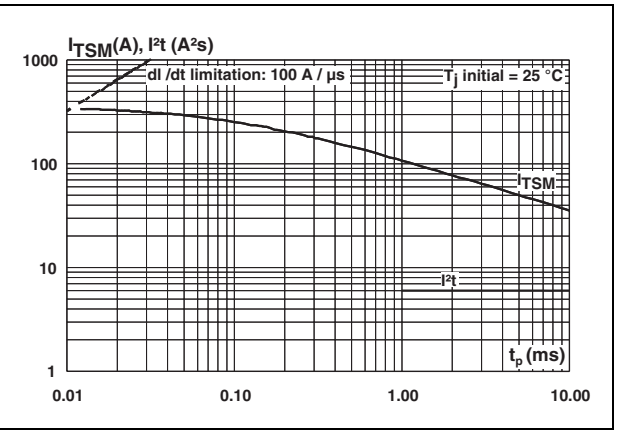


Figure 10. On-state characteristics (maximum values)

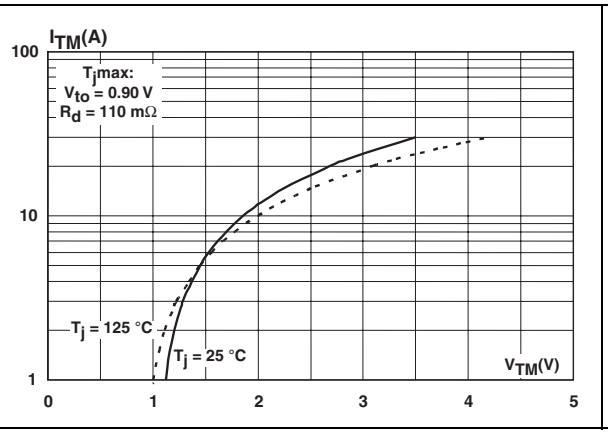


Figure 11. Relative variation of critical rate of decrease of main current $(dI/dt)_c$ versus junction temperature

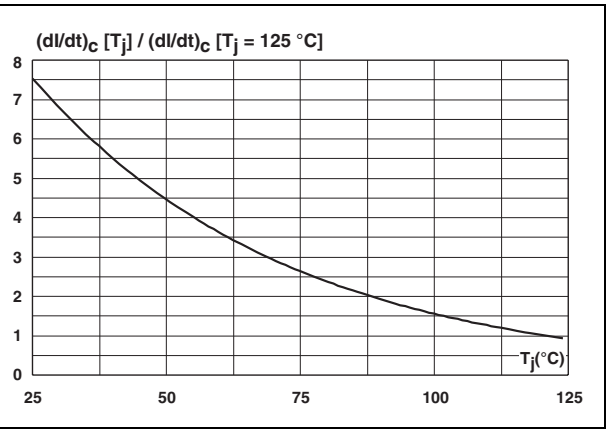


Figure 12. Relative variation of static dV/dt immunity versus junction temperature (gate open)

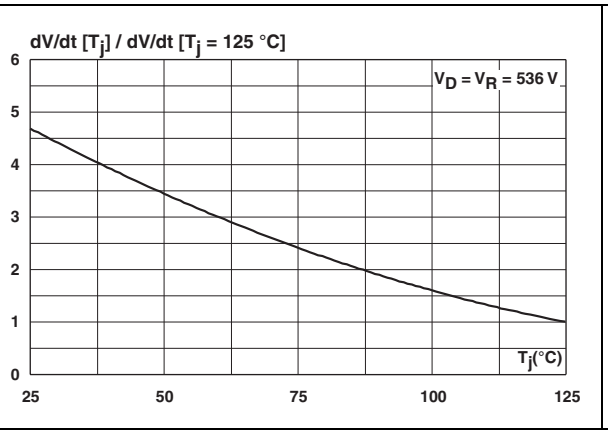


Figure 13. Relative variation of leakage current versus junction temperature

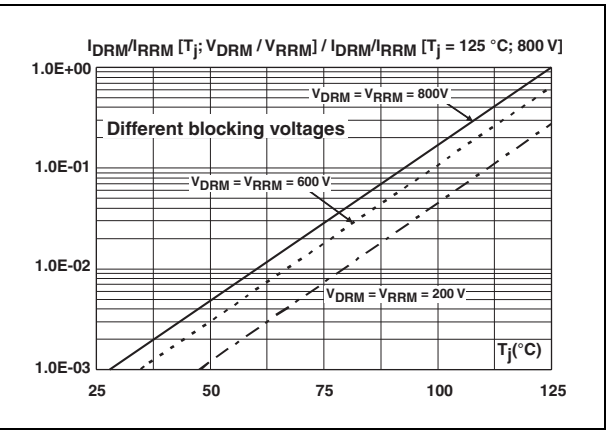


Figure 14. Relative variation of the clamping voltage (V_{CL}) versus junction temperature (minimum values)

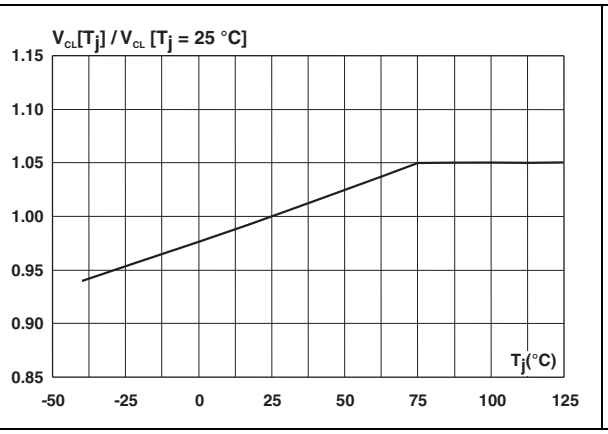
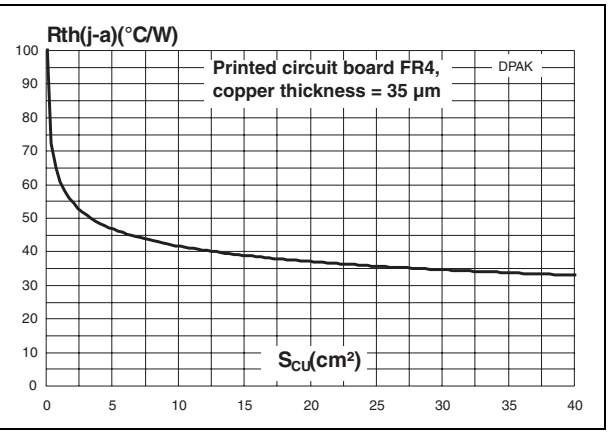


Figure 15. Thermal resistance junction to ambient versus copper surface under tab

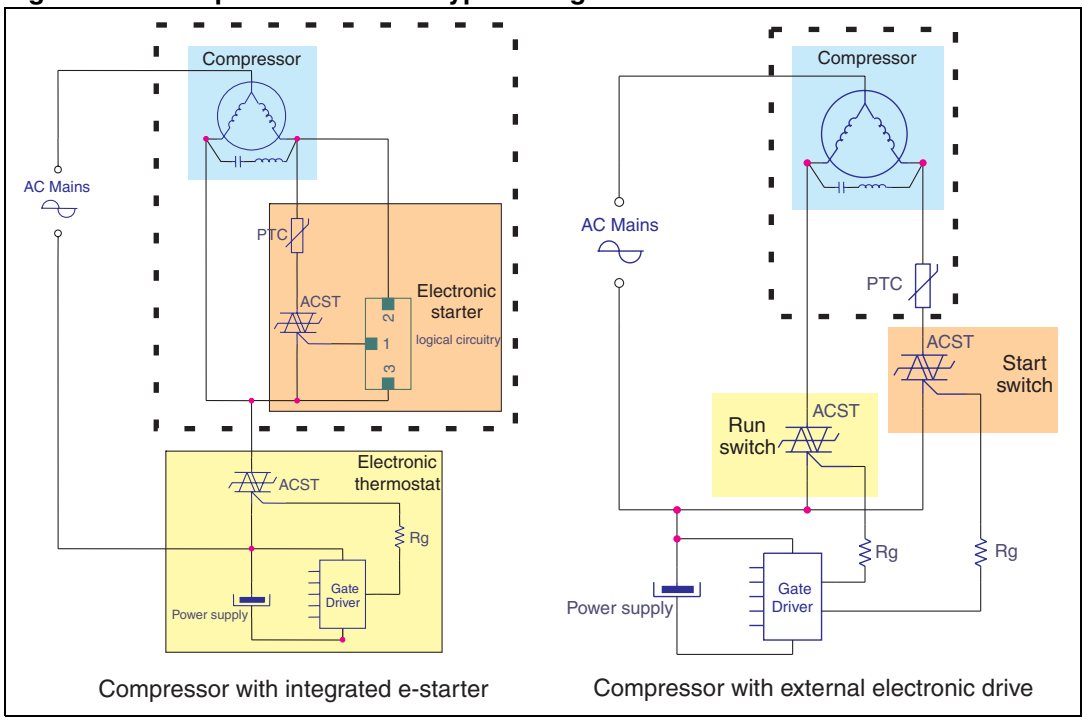


2 Application information

2.1 Typical application description

The ACST4 device has been designed to control medium power load, such as AC motors in home appliances. Thanks to its thermal and turn off commutation performances, the ACST4 switch is able to drive an inductive load up to 4 A with no turn off additional snubber. It also provides high thermal performances in static and transient modes such as the compressor inrush current or high torque operating conditions of an AC motor. Thanks to its low gate triggering current level, the ACST4 can be driven directly by an MCU through a simple gate resistor as shown *Figure 16* and *Figure 17*.

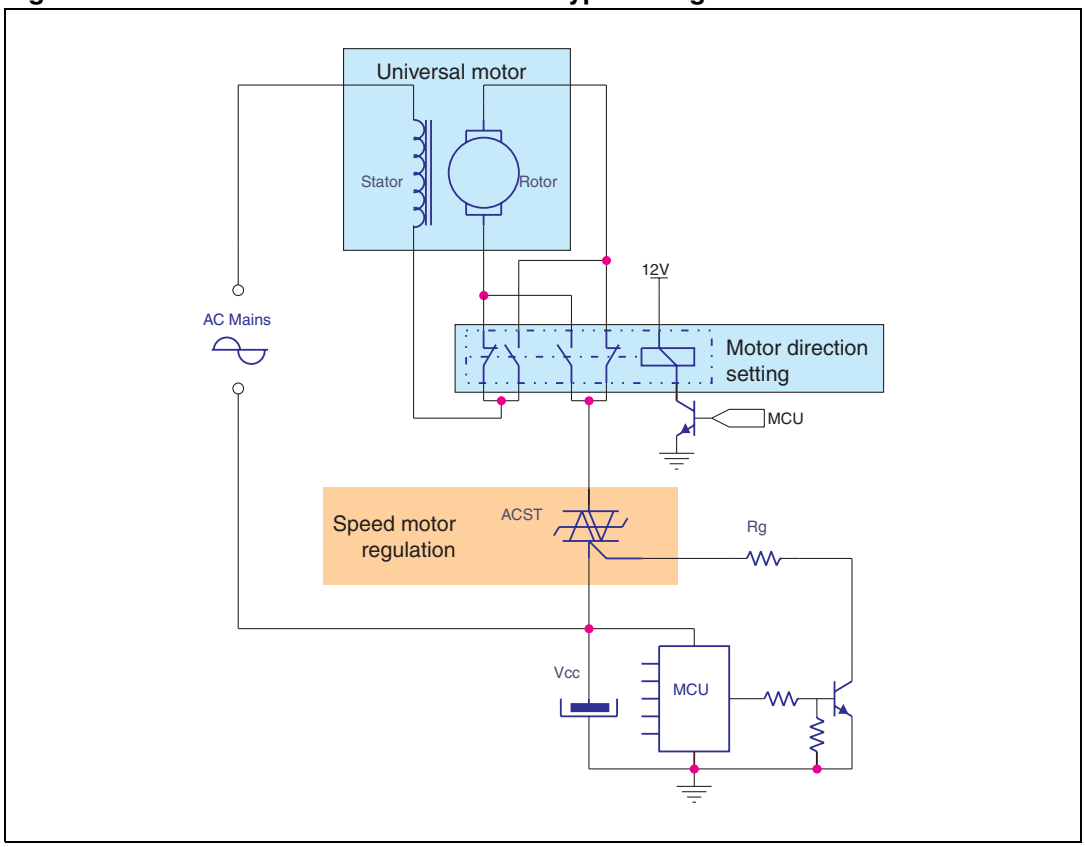
Figure 16. Compressor control – typical diagrams



Compressor with integrated e-starter

Compressor with external electronic drive

Figure 17. Universal drum motor control – typical diagram



2.2 AC line transient voltage ruggedness

In comparison with standard Triacs, which are not robust against surge voltage, the ACST4 is self-protected against over-voltage, specified by the new parameter V_{CL}. The ACST4 switch can safely withstand AC line transient voltages either by clamping the low energy spikes, such as inductive spikes at switch off, or by switching to the on state (for less than 10 ms) to dissipate higher energy shocks through the load. This safety feature works even with high turn-on current ramp up.

The test circuit of *Figure 18* represents the ACST4 application, and is used to stress the ACST switch according to the IEC 61000-4-5 standard conditions. With the additional effect of the load which is limiting the current, the ACST switch withstands the voltage spikes up to 2 kV on top of the peak line voltage. The protection is based on an overvoltage crowbar technology. The ACST4 folds back safely to the on state as shown in *Figure 19*. The ACST4 recovers its blocking voltage capability after the surge and the next zero current crossing. Such a non repetitive test can be done at least 10 times on each AC line voltage polarity.

Figure 18. Overvoltage ruggedness test circuit for resistive and inductive loads for IEC 61000-4-5 standards

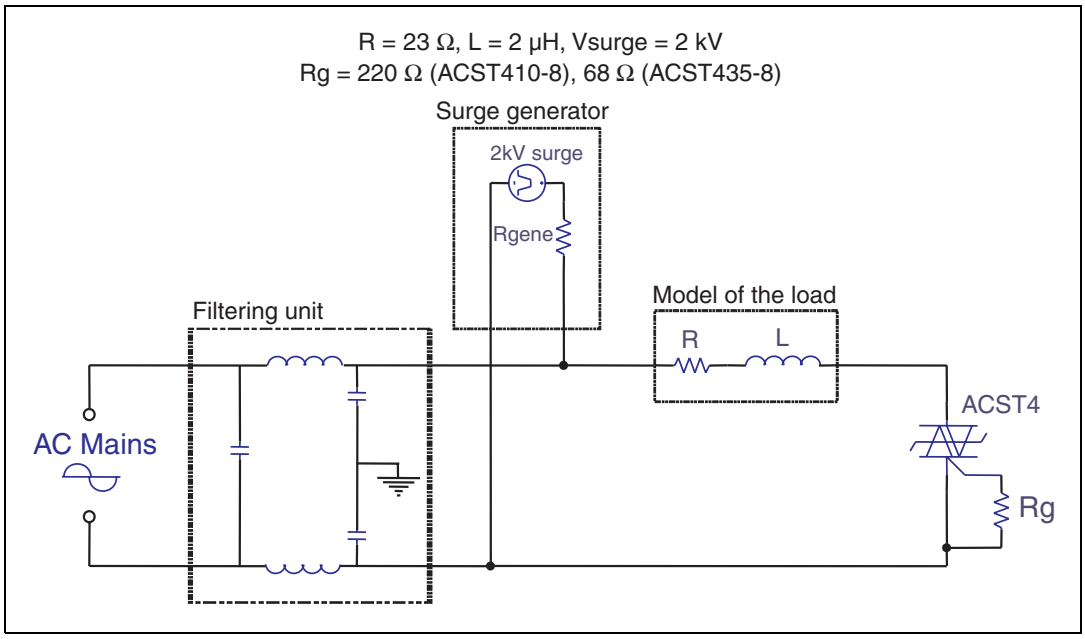
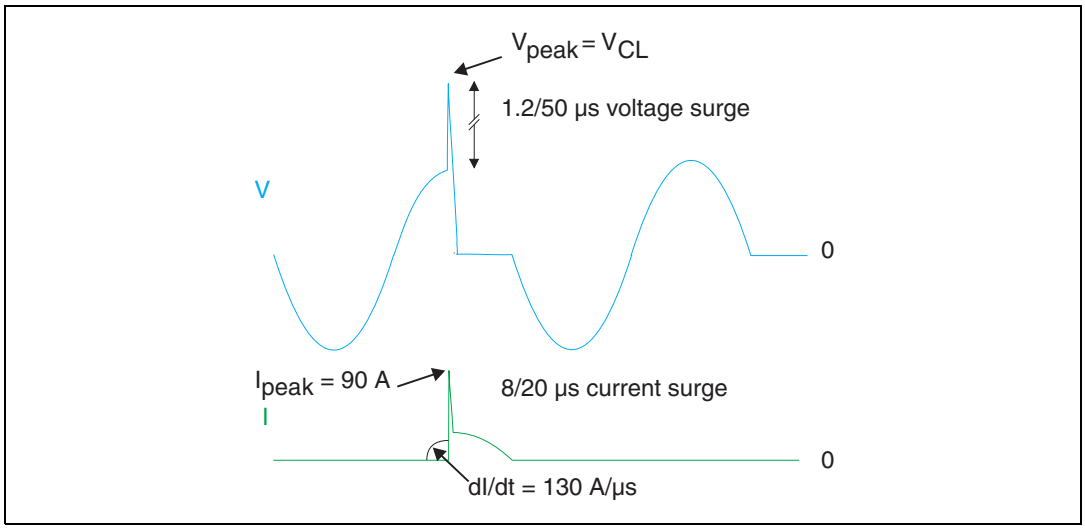
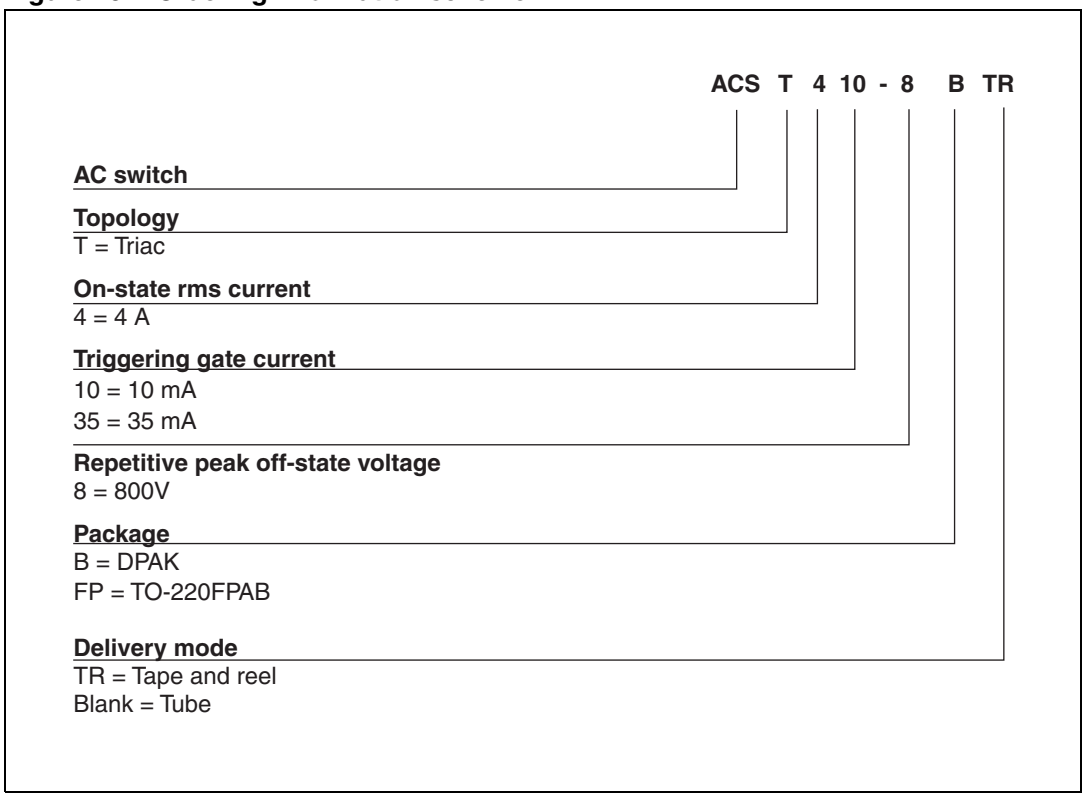


Figure 19. Typical current and voltage waveforms across the ACST4 during IEC 61000-4-5 standard test



3 Ordering information scheme

Figure 20. Ordering information scheme

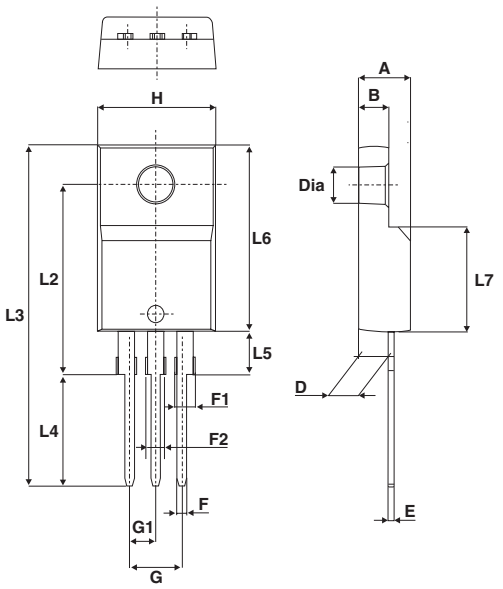


4 Package information

- Epoxy meets UL94, V0
- Cooling method: by conduction (C)
- Recommended torque value(TO220FPAB): 0.4 to 0.6 N·m

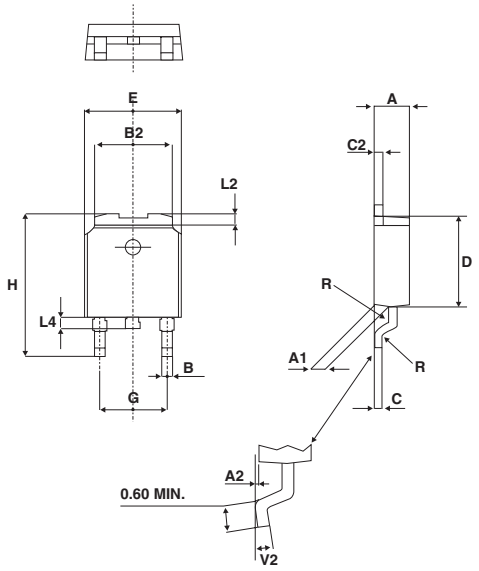
In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: www.st.com. ECOPACK® is an ST trademark.

Table 6. TO-220FPAB dimensions



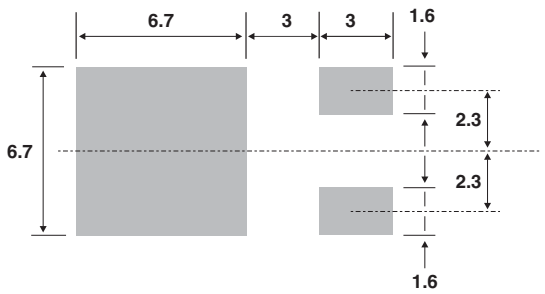
Ref.	Dimensions			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	4.4	4.6	0.173	0.181
B	2.5	2.7	0.098	0.106
D	2.5	2.75	0.098	0.108
E	0.45	0.70	0.018	0.027
F	0.75	1	0.030	0.039
F1	1.15	1.70	0.045	0.067
F2	1.15	1.50	0.045	0.059
G	4.95	5.20	0.195	0.205
G1	2.4	2.7	0.094	0.106
H	10	10.4	0.393	0.409
L2	16 Typ.		0.63 Typ.	
L3	28.6	30.6	1.126	1.205
L4	9.8	10.6	0.386	0.417
L5	2.9	3.6	0.114	0.142
L6	15.9	16.4	0.626	0.646
L7	9.00	9.30	0.354	0.366
Dia.	3.00	3.20	0.118	0.126

Table 7. DPAK dimensions



Ref.	Dimensions			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	2.20	2.40	0.086	0.094
A1	0.90	1.10	0.035	0.043
A2	0.03	0.23	0.001	0.009
B	0.64	0.90	0.025	0.035
B2	5.20	5.40	0.204	0.212
C	0.45	0.60	0.017	0.023
C2	0.48	0.60	0.018	0.023
D	6.00	6.20	0.236	0.244
E	6.40	6.60	0.251	0.259
G	4.40	4.60	0.173	0.181
H	9.35	10.10	0.368	0.397
L2	0.80 typ.		0.031 typ.	
L4	0.60	1.00	0.023	0.039
V2	0°	8°	0°	8°

Figure 21. Footprint (dimensions in mm)



5 Ordering information

Table 8. Ordering information

Order code	Marking	Package	Weight	Base Qty	Delivery mode
ACST410-8B	ACST4108	DPAK	1.5 g	50	Tube
ACST410-8BTR		DPAK	1.5 g	1000	Tape and reel
ACST410-8FP		TO-220FPAB	2.4 g	50	Tube
ACST435-8B	ACST4358	DPAK	1.5 g	50	Tube
ACST435-8BTR		DPAK	1.5 g	1000	Tape and reel
ACST435-8FP		TO-220FPAB	2.4 g	50	Tube

6 Revision history

Table 9. Document revision history

Date	Revision	Changes
Jan-2003	3A	Previous update.
04-Jul-2007	4	Reformatted to current standard. Added package.
18-Dec-2009	5	V_{DRM}/V_{RRM} updated to 800 V. Order codes updated.

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